## NSN 5961-00-430-2054

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View Online at https://aerobasegroup.com/nsn/5961-00-430-2054 **Inclosure Material:** Metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pnp **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 450.0 breakdown voltage, collector-to-base, emitter open and 400.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Precious Material And Location:** Terminal surface gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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